Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	11	FOOTE-RICHARD-W.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 13:38
1.2	1667	438/381	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38
L3	590	438/382	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38
L4	502	438/384	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38
L5	882	257/536	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38
L6	340	257/537	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:39
L7	765	(438/683).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:40
L8	1603	(257/e21.438).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:41

L9	819	(257/e21.004).CCLS.	LIC DCDLIP.	OR	OFF	2006/09/11 13:42
LJ	013	(23//621.00 <del>1</del> ).CCL3.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	UK	OFF	2000/03/11 13:42
L10	182	(257/e21.006).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:42
L11	3	10 and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 13:42
L12	5	triang\$6 with polysilicon with shape and "TiSi.sub.2"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 13:43
L13	1667	438/381	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:43
L14	590	438/382	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:43
L15	502	438/384	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:43
L16	313	438/385	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:43

L17	1069	L16 or L15 or L14 or L13 and triangular	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 13:43
L18	27	shape same triangle and polysilicon same resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 13:44
L19	0	shape same triangle and polysilicon same resistor and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 13:44
L20	25	shape with triangle and polysilicon same resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 13:44
L21	0	shape with triangle with polysilicon same resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 13:44
S2	6	triangular\$2 with polysilicon and titanium	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 14:53
S3	5	triangular\$2 with polysilicon and titanium and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/06/12 03:04
S4	28	triangular\$2 with polysilicon and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 21:30

S5	69	triangular\$2 same polysilicon and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 14:58
S6	22	triangular\$2 same polysilicon and titanium and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 17:23
S7	0	triangular\$2 same polysilicon same titanium and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 14:58
S8	5	triangular\$2 same polysilicon and titanium and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 15:00
S9	24	triangle with polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 17:24
S10	93	triangular\$2 with polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:01
S11	1453	438/381	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38
S12	522	438/382	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38

S13	448	438/384	US-PGPUB;	OR	OFF	2006/00/11 12:20
313	110	130/301	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OK .	OFF	2006/09/11 13:38
S14	272	438/385	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:05
S15	938	S14 or S13 or S12 or S11 and triangular	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:43
S16	49	(S14 or S13 or S12 or S11) and triangular	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:08
S17	191	smith-brad.xa.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:35
S18	0	shape and polysicon same resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:13
S19	1227	shape and polysilicon same resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:14
S20	22	shape same triangle and polysilicon same resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:44

S21	437	shape and polysilicon same resistor and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:21
S22	221	shape and polysilicon same resistor and silicide and titanium	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:21
S23	261	smith-brad\$3.xa.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:38
S24	32	smith-brad\$3-k.xa.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:36
S25	157	gilton-terry-l.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 18:40
S29	0	reistivity same shape and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 18:50
S30	12	resistivity same shape and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 18:52
S31	57	resistivity and shape and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 18:54

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S32	1	resistance same shape and silicide and c49 and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 18:55
S33	0	resistor same shape and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 18:55
S34	0	resistor same polygon and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 18:55
S35	24	resistance same shape and silicide and c49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 19:22
S36	10	FOOTE-RICHARD-W.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 13:38
S37	2730	438/3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 19:19
S38	780	257/536	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:38
S39	305	257/537	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:39

S40	185	resistance same shape and silicide titanium	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/06 21:24
S41	721	(438/683).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:39
S42	294	triangular\$2 same resistivity	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 21:35
S43	11255	triangular\$2 same resistance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/06 21:35
S44	62	triangular\$2 same resistance and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 19:23
S45	12	triang\$4 with polysilicon and titanium and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 18:12
S46	35	polysilicon with c49 with titanium with silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 18:12
S47	0	polysilicon with c49 with titanium with silicide and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 18:13

S48	35	polysilicon with c49 with titanium with silicide	US-PGPUB; USPAT; USOCR;	OR	OFF	2005/12/10 18:13
			EPO; JPO; DERWENT; IBM_TDB			
S49	1214	(trianlge or triangular) with resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/12/10 18:25
S50	17	(trianlge or triangular) with resistor and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/12/10 18:39
S51	80	(trianlge or triangular) same (resistivity or resistor or resistance) and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/12/10 18:40
S52	26	(trianlge or triangular) with (resistivity or resistor or resistance) and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/12/10 19:22
S53	1	wedge with resitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/12/10 19:23
S54	16	triang\$6 with polysilicon with shape	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 19:29
S55	5	triang\$6 with polysilicon with shape and "TiSi.sub.2"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 13:43

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S56	211	c49 with resistance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 19:38
S57	3	c49 with resistance with known	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/10 19:38
S58	4450019	c49 with well known	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/30 10:01
S59	4	c49 with well known	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/05/30 10:01
S60	2	("6281101").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/06/12 03:04

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